

Semiconductors
High-reliability discrete products and engineering services since 1977

C230, C231, C230()3, C231()3, C232, C233 SERIES

## SILICON CONTROLLED RECTIFIERS

## FEATURES

- Available as "HR" (high reliability) screened per MIL-PRF-19500, JANTX level. Add "HR" suffix to base part number.
- Available as non-RoHS ( $\mathrm{Sn} / \mathrm{Pb}$ plating), standard, and as RoHS by adding "-PBF" suffix.

MAXIMUM RATINGS

| Rating | Symbol | Value | Unit |
| :---: | :---: | :---: | :---: |
| Peak repetitive off state voltage ${ }^{(1)}$ $\left(\mathrm{T}_{\jmath}=-40 \text { to }+100^{\circ} \mathrm{C}\right)$ <br> C230F, C231F, C230F3, C231F3, C232F, C233F <br> C230A, C231A, C230A3, C231A3, C232A, C233A <br> C230B, C231B, C230B3, C231B3, C232B, C233B <br> C230C, C231C, C230C3, C231C3, C232C, C233C <br> C230D, C231D, C230D3, C231D3, C232D, C233D <br> C230E, C231E, C230E3, C231E3, C232E, C233E <br> C230M, C231M, C230M3, C231M3, C232M, C233M | $\mathrm{V}_{\text {RRM }}, \mathrm{V}_{\text {DRM }}$ | $\begin{gathered} 50 \\ 100 \\ 200 \\ 300 \\ 400 \\ 500 \\ 600 \end{gathered}$ | Volts |
| Peak non-repetitive reverse voltage $\left(\mathrm{T}_{\jmath}=-40 \text { to }+100^{\circ} \mathrm{C}\right)$ <br> C230F, C231F, C230F3, C231F3, C232F, C233F <br> C230A, C231A, C230A3, C231A3, C232A, C233A <br> C230B, C231B, C230B3, C231B3, C232B, C233B <br> C230C, C231C, C230C3, C231C3, C232C, C233C <br> C230D, C231D, C230D3, C231D3, C232D, C233D <br> C230E, C231E, C230E3, C231E3, C232E, C233E <br> C230M, C231M, C230M3, C231M3, C232M, C233M | $V_{\text {RSM }}$ | $\begin{gathered} 75 \\ 150 \\ 300 \\ 400 \\ 500 \\ 600 \\ 720 \end{gathered}$ | Volts |
| Forward current RMS | $I_{\text {(RMS }}$ | 25 | Amps |
| Peak surge current <br> (one cycle, $60 \mathrm{~Hz}, \mathrm{~T}_{\mathrm{c}}=-40$ to $+100^{\circ} \mathrm{C}$ ) | ITsm | 250 | Amps |
| Circuit fusing considerations $\left(\mathrm{T}_{\mathrm{C}}=-40 \text { to }+100^{\circ} \mathrm{C}, \mathrm{t}=8.3 \mathrm{~ms}\right)$ | $1^{2} \mathrm{t}$ | 260 | $A^{2} \mathrm{~S}$ |
| Peak gate power | $\mathrm{P}_{\mathrm{GM}}$ | 5 | Watts |
| Average gate power | $\mathrm{P}_{\mathrm{G}(\mathrm{AV})}$ | 0.5 | Watts |
| Peak forward gate current | $\mathrm{I}_{\text {GM }}$ | 2 | Amps |
| Operating junction temperature range | TJ | -40 to +100 | ${ }^{\circ} \mathrm{C}$ |
| Storage temperature range | $\mathrm{T}_{\text {stg }}$ | -40 to +125 | ${ }^{\circ} \mathrm{C}$ |
| Mounting torque |  | 30 | In. lb. |

THERMAL CHARACTERISTICS

| Characteristic | Symbol | Maximum | Unit |
| :--- | :---: | :---: | :---: |
| Thermal resistance, junction to case |  |  |  |
| Pressfit | Reлс | 1 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| Isolated stud |  | 1.15 |  |

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ELECTRICAL CHARACTERISTICS ( $\mathrm{T}_{\mathrm{C}}=25^{\circ} \mathrm{C}$ unless otherwise specified)

| Characteristic | Symbol | Min. | Typ. | Max. | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: |
| Peak forward or reverse blocking current <br> (Rated $V_{\text {DRM }}$ or $V_{\text {RRM, }}$, gate open) $\begin{aligned} & \mathrm{T}_{\mathrm{C}}=25^{\circ} \mathrm{C} \\ & \mathrm{~T}_{\mathrm{C}}=100^{\circ} \mathrm{C} \end{aligned}$ | Idrm, $\mathrm{I}_{\text {Rrm }}$ | - | - | $\begin{gathered} 10 \\ 1 \end{gathered}$ | $\mu \mathrm{A}$ <br> mA |
| Forward "on" voltage <br> ( $I_{\text {тм }}=100$ A peak, pulse width $\leq 1 \mathrm{~ms}$, duty cycle $\leq 2 \%$ ) | $V_{\text {TM }}$ | - | - | 1.9 | Volts |
| Gate trigger current (C230, C230()3, C232 series) $\begin{aligned} & \left(V_{D}=12 \mathrm{~V}, R_{L}=120 \Omega\right) \\ & \left(V_{D}=12 \mathrm{~V}, R_{L}=60 \Omega, T_{C}=-40^{\circ} \mathrm{C}\right) \end{aligned}$ | IGt | - | - | $\begin{aligned} & 25 \\ & 40 \end{aligned}$ | mA |
| Gate trigger current (C231, C231()3, C233 series) $\begin{aligned} & \left(V_{D}=12 \mathrm{~V}, R_{L}=120 \Omega\right) \\ & \left(V_{D}=12 \mathrm{~V}, R_{L}=60 \Omega, T_{C}=-40^{\circ} \mathrm{C}\right) \end{aligned}$ | $\mathrm{I}_{\mathrm{GT}}$ |  |  | $\begin{gathered} 9 \\ 20 \end{gathered}$ | mA |
| Gate trigger voltage (continuous dc) $\begin{aligned} & \left(V_{D}=12 \mathrm{~V}, \mathrm{R}_{\mathrm{L}}=120 \Omega\right) \\ & \left(\mathrm{V}_{\mathrm{D}}=12 \mathrm{~V}, \mathrm{R}_{\mathrm{L}}=60 \Omega, \mathrm{~T}_{\mathrm{C}}=-40^{\circ} \mathrm{C}\right) \\ & \left(\mathrm{V}_{\mathrm{D}}=\text { Rated } \mathrm{V}_{\mathrm{DRM}}, R_{\mathrm{L}}=1000 \Omega, \mathrm{~T}_{\mathrm{C}}=100^{\circ} \mathrm{C}\right) \end{aligned}$ | $\mathrm{V}_{\mathrm{GT}}$ | $0.2$ |  | $\begin{gathered} 1.5 \\ 2 \end{gathered}$ | Volts |
| Holding current $\begin{aligned} & \left(\mathrm{V}_{\mathrm{D}}=24 \mathrm{~V} \text {, gate open, } \mathrm{I}_{\mathrm{T}}=0.5 \mathrm{~A}\right) \\ & \mathrm{T}_{\mathrm{C}}=25^{\circ} \mathrm{C} \\ & \mathrm{~T}_{\mathrm{C}}=-40^{\circ} \mathrm{C} \end{aligned}$ | $\mathrm{I}_{\mathrm{H}}$ |  | - | $\begin{gathered} 50 \\ 100 \end{gathered}$ | mA |
| Turn-on time ( $\mathrm{t}_{\mathrm{d}}+\mathrm{t}_{\mathrm{r}}$ ) $\left(I_{T M}=25 \mathrm{~A}, \mathrm{I}_{\mathrm{GT}}=40 \mathrm{~mA}, \mathrm{~V}_{\mathrm{D}}=\text { Rated } \mathrm{V}_{\mathrm{DRM}}\right)$ | $\mathrm{tg}_{\mathrm{gt}}$ | - | 1 | - | $\mu \mathrm{s}$ |
| Turn-off time $\begin{aligned} & \left(I_{т M}=10 \mathrm{~A}, \mathrm{I}_{\mathrm{R}}=10 \mathrm{~A}, \text { pulse width }=50 \mu \mathrm{~s}, \mathrm{dv} / \mathrm{dt}=20 \mathrm{~V} / \mu \mathrm{s},\right. \\ & \left.\mathrm{V}_{\mathrm{D}}=\text { Rated } \mathrm{V}_{\text {DRM }}\right) \\ & \left(\mathrm{T}_{\mathrm{C}}=100^{\circ} \mathrm{C}\right) \end{aligned}$ | $\mathrm{t}_{\text {a }}$ |  | $\begin{aligned} & 25 \\ & 35 \end{aligned}$ |  | $\mu \mathrm{s}$ |
| Forward voltage application rate ( $\mathrm{V}_{\mathrm{D}}=$ rated $\mathrm{V}_{\text {DRM }}, \mathrm{T}_{\mathrm{C}}=100^{\circ} \mathrm{C}$ ) | dv/dt | - | 100 | - | V/ $/ \mathrm{s}$ |

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MECHANICAL CHARACTERISTICS

| Case | Digi PF2 (C232 and C233 SERIES) |
| :--- | :--- |
| Marking | Body painted, alpha-numeric |



|  | DIGI PF2 |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: |
|  | Inches |  |  | Millimeters |  |
|  | Min | Max | Min | Max |  |
| A | 0.501 | 0.505 | 12.730 | 12.830 |  |
| B | 0.465 | 0.475 | 11.810 | 12.060 |  |
| C | 0.330 | 0.380 | 8.390 | 9.650 |  |
| E | 0.100 | - | 2.540 | - |  |
| F | 0.035 | 0.085 | 0.890 | 2.160 |  |
| J | 0.080 | 0.097 | 2.040 | 2.460 |  |
| K | - | 0.800 | - | 20.320 |  |
| N | - | 0.510 | - | 12.950 |  |
| Q | 0.065 | 0.160 | 1.650 | 4.060 |  |

MECHANICAL CHARACTERISTICS

| Case | TO-48 (C230,C231) |
| :--- | :--- |
| Marking | Body painted, alpha-numeric |
| Polarity | Cathode is stud |



|  | TO-48 |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: |
|  | Inches |  |  | Millimeters |  |
|  | Min | Max | Min | Max |  |
| CD | - | 0.543 | - | 13.793 |  |
| CH | - | 0.550 | - | 13.970 |  |
| HF | 0.544 | 0.563 | 13.817 | 14.301 |  |
| OAH | - | 1.193 | - | 30.303 |  |
| SL | 0.422 | 0.453 | 10.718 | 11.507 |  |
| ФT | 0.125 | 0.165 | 3.175 | 4.191 |  |
| $\boldsymbol{\Phi T}_{\mathbf{1}}$ | 0.060 | 0.075 | 1.524 | 1.905 |  |

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MECHANICAL CHARACTERISTICS

| Case | TO-48 ISO (C230()3, C231()3 SERIES) |
| :--- | :--- |
| Marking | Body painted, alpha-numeric |
| Polarity | Cathode is stud |



|  | TO-48 ISO |  |  |  |
| :---: | :---: | :---: | :---: | :---: |
|  | Max |  |  | Min |
|  | Inches |  | Max |  |
|  | Min | Maxeters |  |  |
| A | 0.551 | 0.559 | 14.000 | 14.200 |
| B | 0.501 | 0.505 | 12.730 | 12.830 |
| C | - | 1.280 | - | 32.510 |
| F | - | 0.160 | - | 4.060 |
| H | - | 0.265 | - | 6.730 |
| J | 0.420 | 0.455 | 10.670 | 11.560 |
| K | 0.300 | 0.350 | 7.620 | 8.890 |
| L | 0.255 | 0.275 | 6.480 | 6.990 |
| Q | 0.055 | 0.085 | 1.400 | 2.160 |
| T | 0.135 | 0.150 | 3.430 | 3.810 |



